

DECLARATION FOR PATENT APPLICATION

Attorney Docket:

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As a below-named inventor(s), I/we hereby declare that:

My/Our residence(s), post office address(es) and citizenship(s) is/are as stated below next to my/our name(s).

I/We believe I/we am/are the original inventor, first and sole (if only one name is listed below) or the original, first and joint inventors (if plural names are listed below) of the subject matter which is claimed, and for which a patent is sought on the invention entitled: Fan Out Type Wafer Level Package Structure and Method of the Same

the specification of which: (check one) [ ] is attached hereto.

[X]	was filed on <u>Dec. 3, 2003</u> ,	as Serial No.	_10/725,933
	and was amended on		(if applicable).

We hereby state that we have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

We acknowledge the duty to disclose information which is material to the patentability of this application as defined by 37 CFR ' 1.56.

We hereby claim foreign priority benefits under 35 U.S.C. '119 of any foreign application(s) for patent or inventor's certificate listed below, and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prior Foreign Applications:

(Application No.)	(Country)	(Day/Month/Year Filed)	[] Yes	[ ] No
(Application No.)	(Country)	(Day/Month/Year Filed)	[ ] Yes	[ ] No
(Application No.)	(Country)	(Day/Month/Year Filed)	[] Yes	[ ] No

We hereby appoint Gary M. Nath, Reg. No. 26,965; Harold L. Novick, Reg. No. 26,011; Todd L. Juneau, Reg. No. 40,669; Lee C. Heiman, Reg. No. 41,827; Jerald L. Meyer, Reg. No. 41,194; Joshua B. Goldberg, Reg. No. 44,126; Marvin C. Berkowitz, Reg. No. 47,421; Sheldon McGee, Reg. No. 50,454; Tanya E. Harkins, Reg. No. 52,993; Robert C. Ryan, Reg. No. 29,343; and Derek Richmond, Reg. No. 45,771; as my attorneys to prosecute this application and transact all business in the U.S. Patent and Trademark Office connected therewith.

Direct Telephone Calls to:

Send Correspondence to: NATH & ASSOCIATES, PLLC Sixth Floor 1030 15th Street, N.W. Washington, D.C. 20005 U.S.A.

Gary M. Nath (202) 775-8383

We hereby claim the benefit under 35 U.S.C. '120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by 35 U.S.C. '112, first paragraph, I/we acknowledge the duty to disclose material information as defined in 37 CFR '1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

(U.S.	Application Serial No.)	(U.S.	Filing Date)	(Statuspatented,	pending,	abandoned)
(U.S.	Application Serial No.)	(U.S.	Filing Date)	 (Statuspatented,	pending,	abandoned)

## DECLARATION FOR PATENT APPLICATION

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'I/we hereby claim the benefit under 35 U.S.C. 119(e) of any United States provisional application(s) listed below:

We hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements are made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 U.S.C. '1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.  Full name of sole or first inventor: Wen-Kun Yang  Inventor's Signature  Residence: No. 47, Lane 6, Ankang St., Hsinchu, Taiwan 300, R.O.C.  Country of Citizenship: Taiwan (R.O.C.)  Full name of second inventor: Wen-Pin Yang  Inventor's Signature  A. A. B. Date: 12/12/D3  Residence: No. 112, Julian St., Hsinchu, Taiwan 300, R.O.C.  Country of Citizenship: Taiwan (R.O.C.)  Post Office Address:	Application Number(s) Filing Date	
Full name of second inventor: Wen-Pin Yang  Inventor's Signature 12/12/03  Residence: No. 112, Julian St., Hsinche, Taiwan 300, R.O.C.  Country of Citizenship: Taiwan (R.O.C.)	made on information and belief are believed to be true; and further that these statements are made with knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or bunder 18 U.S.C. '1001 and that such willful false statements may jeopardize the validity of the applica or any patent issued thereon.  Full name of sole or first inventor: Wen-Kun Yang  Inventor's Signature  Date: 12 6 6  Residence: No. 47, Lane 6, Ankang St., Hsinchu, Taiwan 300, R.O.C.	the oth,
Full name of second inventor: Wen-Pin Yang  Inventor's Signature	Country of Citizenship: Taiwan (R. O. C.)	
Inventor's Signature	Post Office Address:	
	Inventor's Signature	

Full name	or thi	ra inve	nggr: <u>Sinin</u>	LI Che	<u>n                                     </u>	<del></del>		12.7	
Inventor's	Signa	ture	Shih -li	Cho	$\sim$		Date:_	12/1	1/109
Residence:	7F.,	No.22,	Sanchong	Rd.,	Jhudong	Township,	Hsinchu	County,	Taiwan
	310, R	.o.c.	4 4894.4.4			_			

Country of Citizenship: Taiwan (R. O. C.)

Post Office Address: \_\_